#### 查询SN75140供应商

# 捷多邦,专业PCB打样工厂,24小时加急出货 SN75140 DUAL LINE RECEIVER

P OR PS<sup>†</sup> PACKAGE

(TOP VIEW)

8 VCC

7

5

10UT

1LINE

GND

SN75140 PSR).

3

<sup>†</sup>The PS package is only available left-ended taped and reeled (order

COMSTRB

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20UT

6 COMREF

2LINE

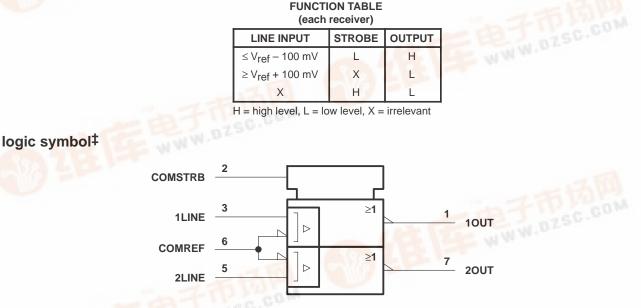
- Single 5-V Supply
- ±100-mV Sensitivity
- For Application as:
  - Single-Ended Line Receiver
  - Gated Oscillator
  - Level Comparator
- Adjustable Reference Voltage
- TTL Outputs
- TTL-Compatible Strobe
- Designed for Party-Line (Data-Bus) Applications
- Common Reference-Voltage Pin
- Common Strobe

#### description

This device consists of a dual single-ended line receiver with TTL-compatible strobes and outputs. The reference voltage (switching threshold) is applied externally and can be adjusted from 1.5 V to 3.5 V, making it possible to optimize noise immunity for a given system design. Due to the low input current (less than  $100 \,\mu$ A), the device is suited ideally for party-line (data-bus) systems.

The SN75140 has a common reference-voltage pin and a common strobe.

The SN75140 is characterized for operation from 0°C to 70°C.



<sup>‡</sup>This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

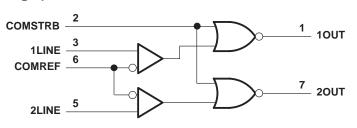


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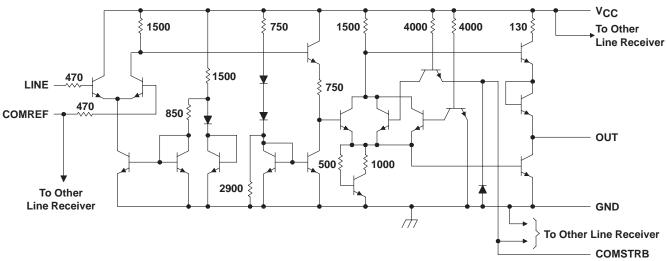


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#### logic diagram (positive logic)



#### schematic (each receiver)



NOTE: Resistor values shown are nominal and in ohms.

#### absolute maximum ratings over operating free-air temperature range (unless otherwise noted)<sup>†</sup>

Supply voltage, V <sub>CC</sub> (see Note 1)	
Reference input voltage, V <sub>ref</sub>	5.5 V
Line input voltage range with respect to GND	
Line input voltage with respect to V <sub>ref</sub>	±5 V
Strobe input voltage	
Continuous total power dissipation	See Dissipation Rating Table
Storage temperature range, T <sub>stg</sub>	–65°C to 150°C
Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds	260°C

<sup>+</sup> Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTE 1: Unless otherwise specified, voltage values are with respect to network ground terminal.

DISSIPATION RATING TABLE						
PACKAGE	T <sub>A</sub> ≤ 25°C POWER RATING	DERATING FACTOR ABOVE T <sub>A</sub> = 25°C	T <sub>A</sub> = 70°C POWER RATING			
Р	1000 mW	8.0 mW/°C	640 mW			
PS	450 mW	3.6 mW/°C	288 mW			



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#### recommended operating conditions

	MIN	NOM	MAX	UNIT
Supply voltage, V <sub>CC</sub>	4.5	5	5.5	V
Reference input voltage, V <sub>ref</sub>	1.5		3.5	V
High-level line input voltage, VIH(L)	V <sub>ref</sub> +0.1		V <sub>CC</sub> -1	V
Low-level line input voltage, VIL(L)	0		V <sub>ref</sub> -0.1	V
High-level strobe input voltage, VIH(S)	2		5.5	V
Low-level strobe input voltage, VIL(S)	0		0.8	V
Operating free-air temperature range, T <sub>A</sub>	0		70	°C

#### electrical characteristics over recommended operating $V_{CC}$ = 5 V $\pm 10\%,\,V_{ref}$ = 1.5 V to 3.5 V (unless otherwise noted) free-air temperature range,

PARAMETER		TEST CONDITIONS		MIN	TYP <sup>†</sup>	MAX	UNIT		
VIK	Strobe input clam	p voltage	I <sub>I(S)</sub> = -12 mA					-1.5	V
VOH	High-level output	voltage	$V_{IL(L)} = V_{ref} - 100 \text{ mV},$	V <sub>IL(S)</sub> = 0.8 V,	I <sub>OH</sub> = -400 μA	2.4			V
V <sub>OL</sub> Low-level output voltage		$V_{IH(L)} = V_{ref} + 100 \text{ mV},$	V <sub>IL(S)</sub> = 0.8 V,	I <sub>OL</sub> = 16 mA			0.4		
		/oltage	$V_{IL(L)} = V_{ref} - 100 \text{ mV},$	V <sub>IH(S)</sub> = 2 V,	I <sub>OL</sub> = 16 mA			0.4 V	V
II(S) Strobe input current at maximum input voltage	Strobe					1	mA		
	COMSTRB	$V_{I(S)} = 5.5 V$			2				
		Strobe				40			
High-level IH input current	COMSTRB	$V_{I(S)} = 2.4 V$			80				
	LINE	V <sub>I(L)</sub> = 3.5 V,	V <sub>ref</sub> = 1.5 V			35	100	μA	
	Reference	$V_{I(L)} = 0,$ $V_{ref} = 3.5 V$	V . 25V		35	100			
	COMREF				70	200			
		Strobe				-1.6	A		
	COMSTRB	$\forall I(S) = 0.4 \forall$			-3.2	mA			
ЧL	Low-level IL input current	$V_{1}(1) = 0$ $V_{rot} = 1.5 V$				-10			
		Reference		V <sub>ref</sub> = 0			-10	μA	
		COMREF					-20		
los	Short-circuit output	ut current‡	V <sub>CC</sub> = 5.5 V			-18		-55	mA
ІССН	Supply current, or	utput high	$V_{I(S)} = 0,$	$V_{I(L)} = V_{ref} - 1$	00 mV		18	30	mA
ICCL	Supply current, or	utput low	$V_{I(S)} = 0,$	$V_{I(L)} = V_{ref} + 1$	1		20	35	mA

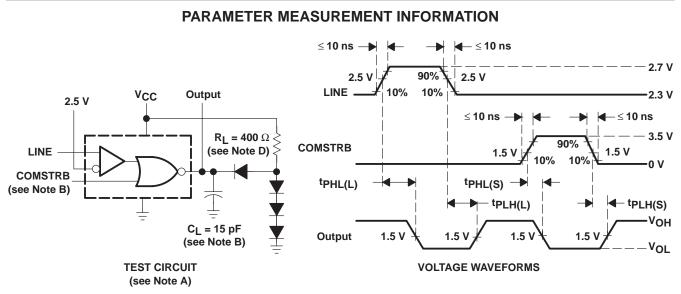
<sup>†</sup> All typical values are at  $V_{CC}$  = 5 V,  $T_A$  = 25°C. <sup>‡</sup> Only one output should be shorted at a time.

# switching characteristics, V<sub>CC</sub> = 5 V, V<sub>ref</sub> = 2.5 V, T<sub>A</sub> = 25°C

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
<sup>t</sup> PLH(L)	Propagation delay time, low- to high-level output from LINE	$C_L = 15 \text{ pF}, R_L = 400 \text{ k}\Omega,$ See Figure 1		22	35	ns
<sup>t</sup> PHL(L)	Propagation delay time, high- to low-level output from LINE	$C_L = 15 \text{ pF}, R_L = 400 \text{ k}\Omega,$ See Figure 1		22	30	ns
<sup>t</sup> PLH(S)	Propagation delay time, low- to high-level output from COMSTRB	$C_L = 15 \text{ pF}, \text{ R}_L = 400 \text{ k}\Omega,$ See Figure 1		12	22	ns
<sup>t</sup> PHL(S)	Propagation delay time, high- to low-level output from COMSTRB	$C_L = 15 \text{ pF}, R_L = 400 \text{ k}\Omega,$ See Figure 1		8	15	ns



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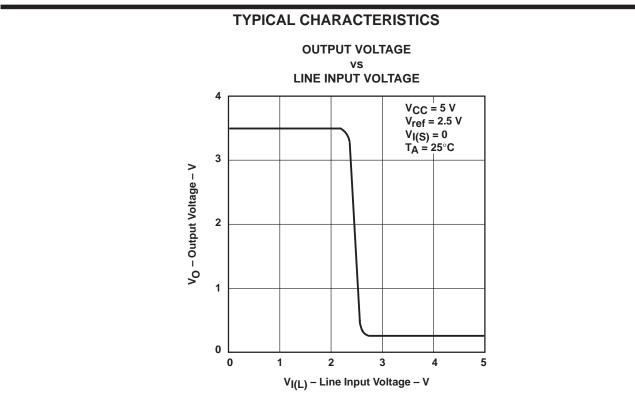


- NOTES: A. Input pulses are supplied by generators having the following characteristics: PRR  $\leq$  1 MHz, duty cycle  $\leq$  50%, Z<sub>O</sub> = 50  $\Omega$ .
  - B. Unused strobes are to be grounded.

C. CL includes probe and jig capacitance.

D. All diodes are 1N3064.

#### Figure 1. Test Circuit and Voltage Waveforms







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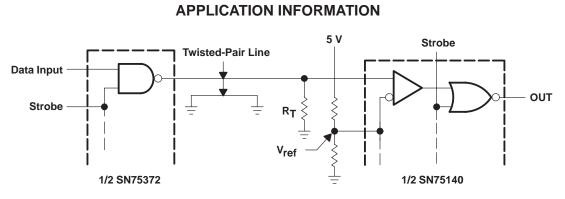
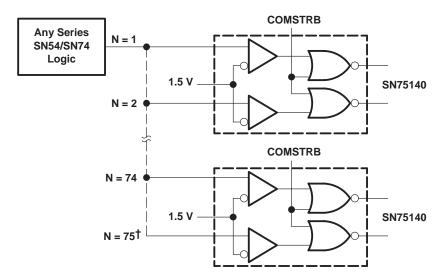


Figure 3. Line Receiver

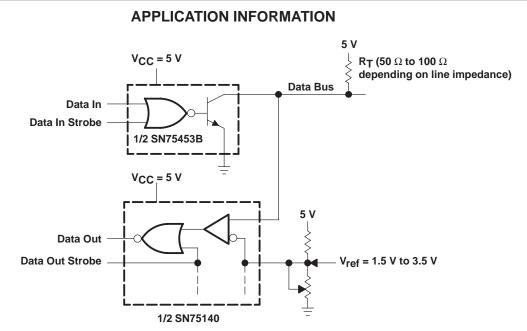


<sup>†</sup> Although most series SN54/SN74 circuits have a >2.4-V output at 400 μA, they typically are capable of maintaining a >2.4-V output level under a load of 7.5 mA.

### Figure 4. High Fanout From Standard TTL Gate



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NOTE A: Using this arrangement, as many as 100 transceivers can be connected to a single data bus. The adjustable reference-voltage feature allows the noise margin to be optimized for a given system. The complete dual bus transceiver (SN75453B driver and SN75140 receiver) can be assembled in approximately the same space required by a single 16-pin package and only one power supply is required (5 V). Data in and data out are TTL compatible.



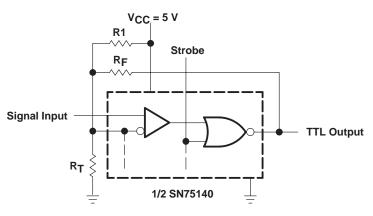
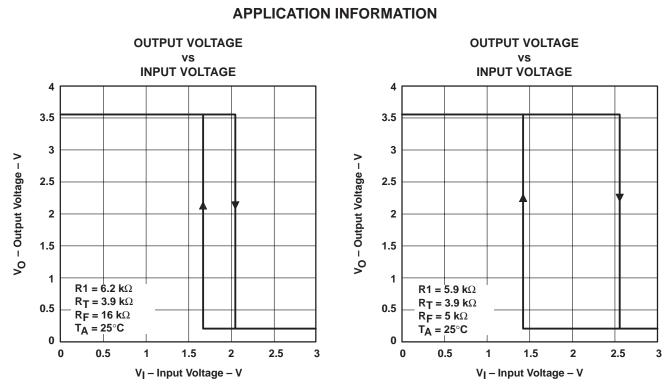


Figure 6. Schmitt Trigger



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NOTE A: Slowly changing input levels from data lines, optical detectors, and other types of transducers can be converted to standard TTL signals with this Schmitt-trigger circuit. R<sub>1</sub>, R<sub>F</sub>, and R<sub>T</sub> can be adjusted for the desired hysteresis and trigger levels.



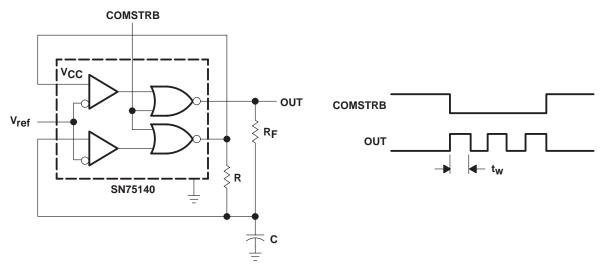
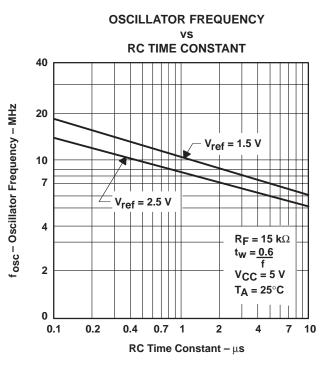


Figure 8. Gated Oscillator



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**APPLICATION INFORMATION** 

Figure 9



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